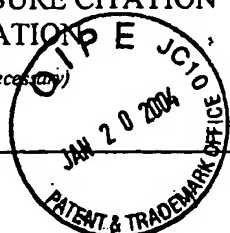


<b>Form PTO-1449</b>  <b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b> <i>(Use several sheets if necessary)</i>	Docket Number 559502000800	Application Number 10/730,190
	Applicant Masayuki EHIRO et al.	
	Filing Date December 4, 2003	Group Art Unit Not Yet Assigned
	Mailing Date January 13, 2004	



## U.S. PATENT DOCUMENTS

Examiner Initials	Ref. No.	Date	Document No.	Name	Class	Subclass	Filing Date If Appropriate

## FOREIGN PATENT DOCUMENTS

Examiner Initials	Ref. No.	Date	Document No.	Country	Class	Subclass	Translation YES NO
DL	1.	01/29/1993	JP 5-21740	Japan			Abstract
DL	2.	07/19/2002	JP 2002-203392	Japan			Abstract

## OTHER DOCUMENTS

(including author, title, Date, Pertinent Pages, Etc.)

Examiner Initials	Ref. No.	Title
DL	3.	Liu, S. Q. et al. (2001). "A New Concept for Non-Volatile Memory: The Electric-Pulse Induced Resistive Change Effect in Colossal Magnetoresistive Thin Films," Non-Volatile Memory Technology Symposium Proceedings pp. 1-7, includes 32 supplemental presentation slides.

EXAMINER:

DATE CONSIDERED:

1/05

EXAMINER: Initial if citation considered, whether or not the citation conforms with MPEP 609. Draw a line through the citation if not in conformance and not considered. Include a copy of this form with next communication to applicant.